

ATDI

Doctoral School on Material Sciences and Technologies
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Óbuda
University

Semester Report - Fall 2022/2023

**Modeling lead-free interconnect reliability
under creep in advanced packaging.**

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Contents

▶ Introduction

- ▶ Modeling set up
- ▶ Plain stress vs Plain strain

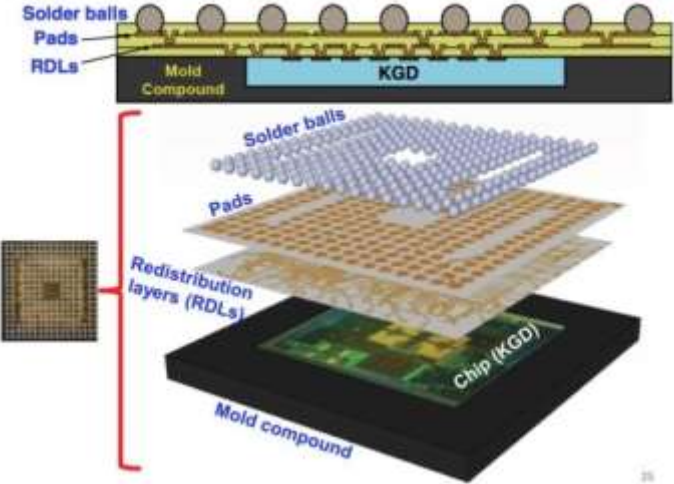
▶ Results

- ▶ Previous semesters.
- ▶ Current semester.

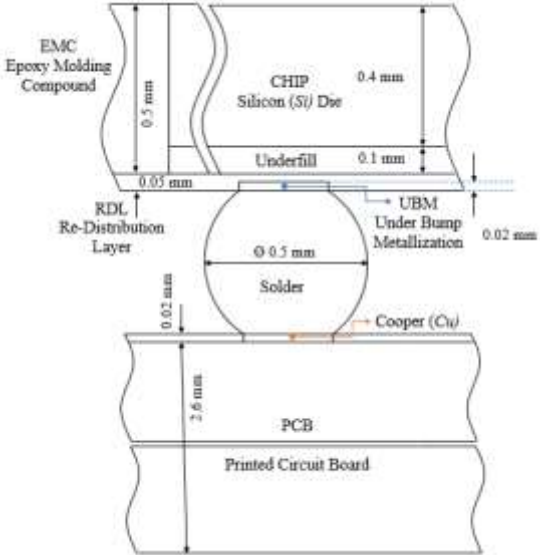
▶ Conclusions

Fan Out Wafer Level Packaging

Fan-Out eWLP (Embedded Wafer-Level Packaging)

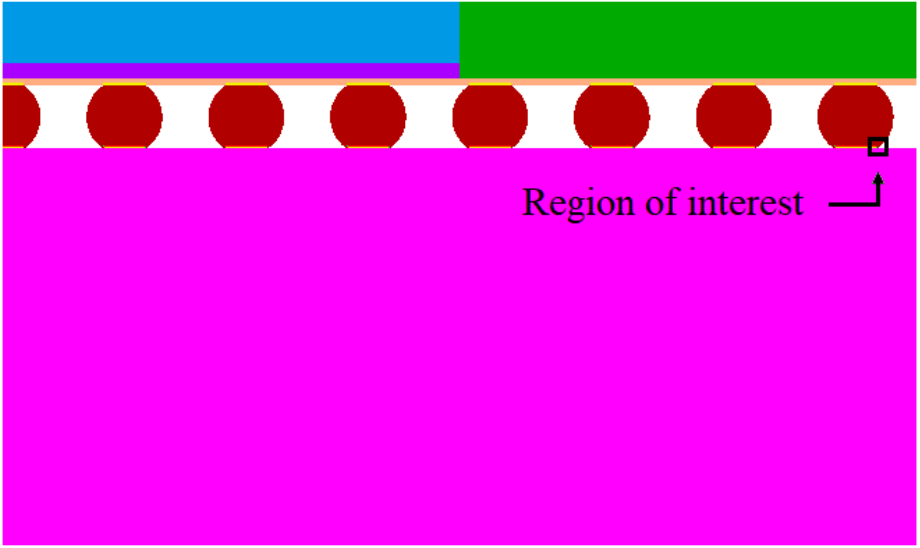


Exploded view



2D Layout

- PCB
- Solder
- Cu_3Sn
- Cu_6Sn_5
- Chip
- Cu
- EMC
- RDL
- Underfill



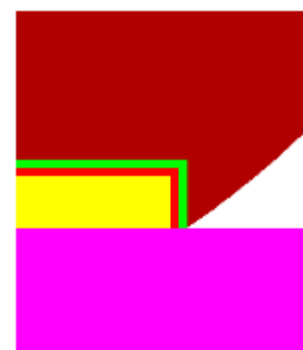
2D Model

Added Value

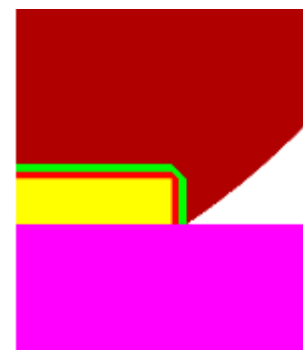
SUMMARY OF STUDY CASES

Element	Material
2D / 3D	SAC305 / SACQ
IMC	Edge
NI / I*	Sharp / Chamfer

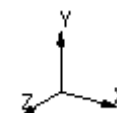
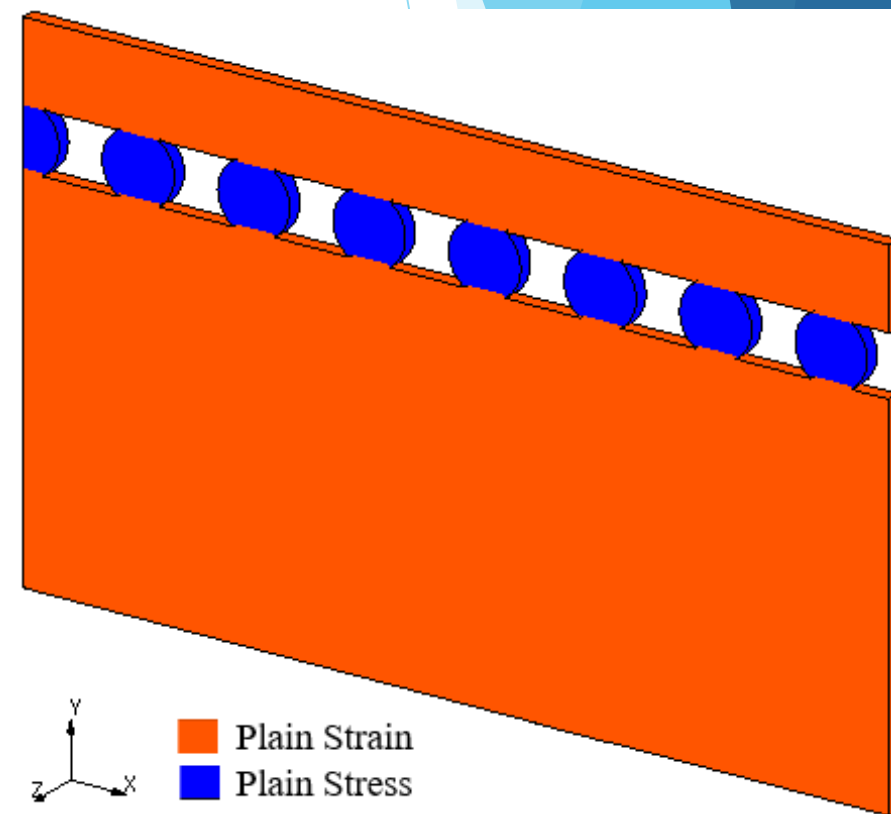
*NI: No IMC layers included, I: IMC layers included



SHARP EDGE



CHAMFER



■ Plain Strain
■ Plain Stress

Results - previous semesters

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Creep and Reliability Prediction of a Fan-Out WLP Influenced by the Visco-Plastic Properties of the Solder

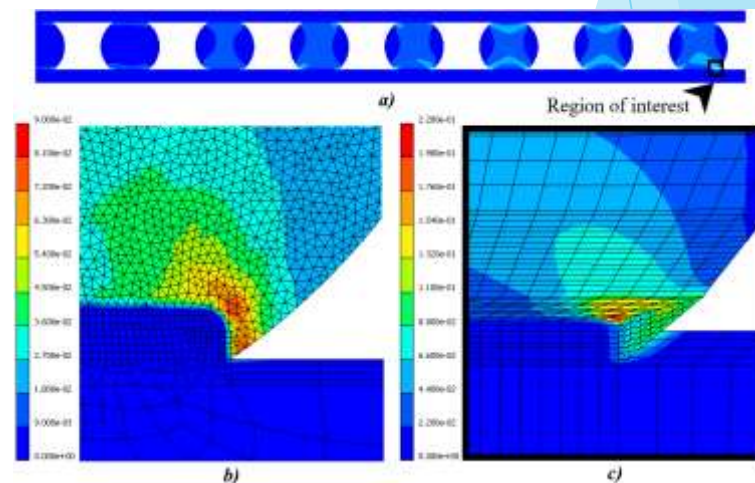
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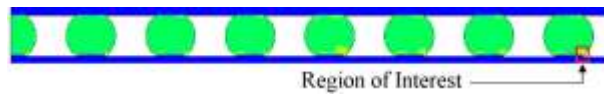
Most relevant conclusion

A change in the copper pad profile shape (squared to rounded) shows a stress reduction and, therefore, more stable creep curves. Additionally, it accentuates the difference of creep values between materials by nearly 16% regarding strain.

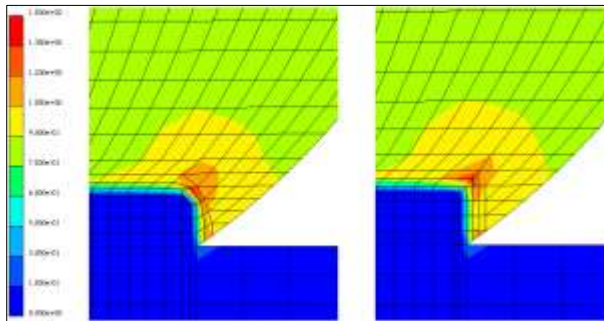


Results - current semester (1/2)

Creep and Strain Energy analysis of a FO-WLP simulation influenced by Cu pad geometry, and IMC



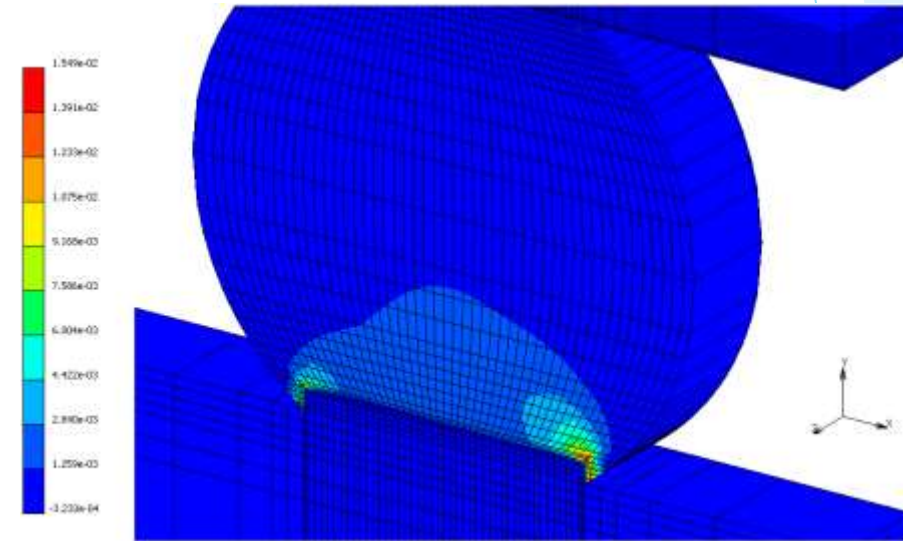
a)



b)

c)

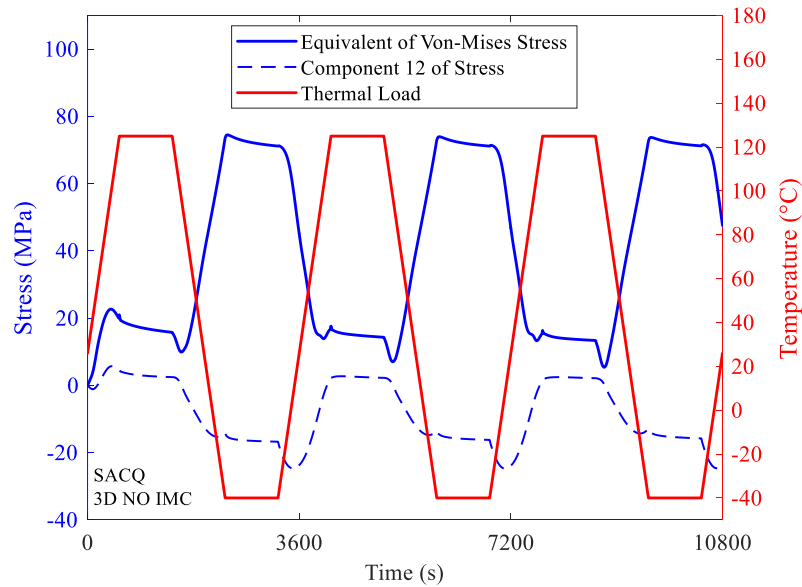
Total Equivalent of Creep Strain at the end of the three cycles: a) TECS distribution along the solder bumps (cropped image), augmented contour band graph of TECS distribution at the vicinity of the critical node, b) Chamfer Cu pad profile, and; c) Sharp Cu pad profile.



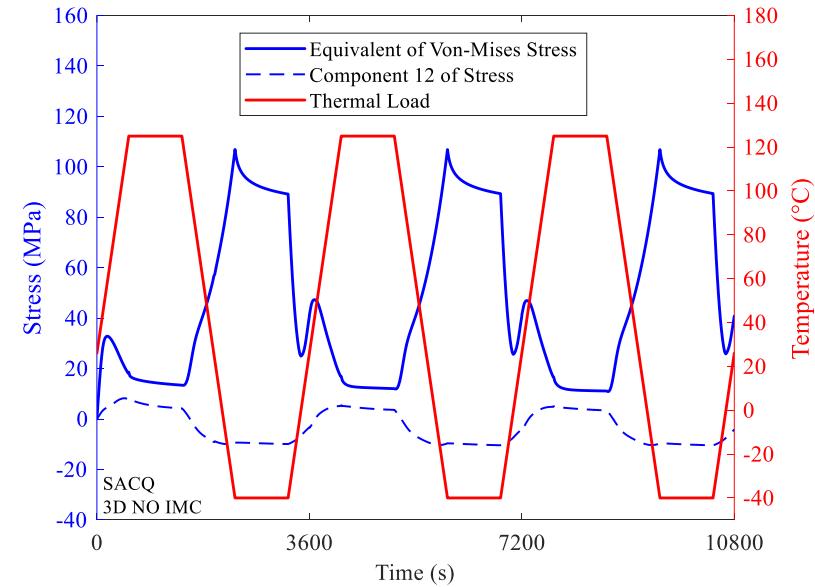
Total Equivalent of Creep Strain at the end of the three cycles. 3D-Sharp-SAC305-IMC included case.

Results - current semester (2/2)

Effect of the bond pad geometry



Chamfer



Sharp

Von Mises Stress and Stress Component 12 (S_{12}) vs. Thermal Load

Thanks for your kind attention

Questions?